

MCS150N120T3C3

V_{CE}	$I_{c\ nom}$
1200V	150A

C3



DESCRIPTION

MCS150N120T3C3 modules using JSCJ's third generation IGBT technology which has advanced Trench and FS(Field Stop) Structure, have very low Collector Emitter Saturation Voltage, can easy to use in drives and inverters.

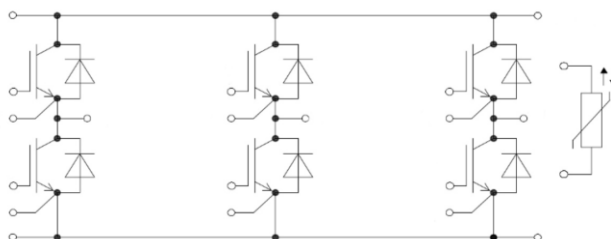
Features

- Low $V_{ce(sat)}$ and positive temperature coefficient
- Low switching loss
- Standard housing
- Solder contact technology

● Application

- Motor Driver
- Inverter
- Servo

EQUIVALENT CIRCUIT



Order Code	Package	Marking	Parking
MCS150N120T3C3	C3	MCS150N120T3C3	Module



JIANGSU CHANGJING ELECTRONICS TECHNOLOGY CO., LTD.

IGBT Discrets & Modules

感谢您的支持，如需要完整规格书，请联系：<igbt.list@jscj-elec.com>，谢谢！

Thank you for your support. If you need a complete datasheet, please contact:

<igbt.list@jscj-elec.com>. Thank you!